NSN 5961-01-371-1354

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-371-1354 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.055 inches and 0.090 inches **Mounting Method:** Terminal **Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 71.4 regulator voltage, dc and 52.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 2.50 microamperes collector current, dc peak **Power Rating Per Characteristic:** 400.0 milliwatts any acceptable preset **Special Features:** Bonded double plug constructed; junction pattern arrangement: pn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/117 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No